

Peculiarities of the composition and structure of the compounds of the rare-earth-Ni-In systems

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Abstract

Data on the composition and structure of 117 ternary compounds of the rare-earth metals, nickel and indium were generalized. Relations between the structure, the metric parameters of the unit cell and valence state of the atoms were considered. © 1997 Elsevier Science S.A.

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1. Introduction.

In recent years ternary intermetallic compounds of indium, rare-earths (R) and transition metals have attracted attention from researchers. Many of these compounds have interesting physical properties. The greatest number of such compounds have been found in the R-Ni-In systems. The first ternary indides of Ni and a rare-earth with equiatomic composition were synthesized and investigated by Ferro et al. [1]. Later we found new compounds and described their crystal structure during a study of isothermal sections of the phase diagrams of the R-Ni-In systems [2-19].

The aim of the present work is a generalization of the data and a search for the peculiarities of the composition and crystal structure of the compounds of the R-Ni-In systems.

2. Experimental details

The alloys were prepared by melting compact metals of high purity in an electrical arc furnace under Ar atmosphere. The investigation of the crystal structure of the compound was carried out by the powder method (diffractometers DRON-2.0, DRON-3M, DRON-4.07, HZG-4a) and the single crystal method (autodiffractometers Syntex P1, Syntex P2₁, DARCH-

1, KM-4). The package of programs CSD [20] was used for solving the structure of the compounds.

3. Results and discussion

Data for the 117 ternary compounds of the R-Ni-In systems for which the crystal structure has been determined are listed in Table 1. In spite of the incomplete data on the investigation of the isothermal sections it is possible to conclude that the elements of the cerium subgroup form more compounds than do those of the yttrium subgroup. The region of the existence of the above indicated compounds is between 8.3 and 63.2 at.% R and between 5.3 and 66.7 at.% In. The lowest R content for the formation of the compounds in R-Cu-In is equal to 7.1 at.% and 7.7 at.% (compounds with the NaZn₁₃ [21] and ThMn₁₂ [22] type structure, respectively) and to 14.3 at.% in the R-Co-In systems (compounds with the HoCoGa₅ [23] type structure). Minimum R content for the formation of the compounds in the R-(Co,Ni,Cu)-In systems decreases at the transition from Co to Cu. In the case of Pr₂Ni₁₆In [= Pr₂(Ni,In)₁₇], the stabilization by indium of the Th₂Ni₁₇ structure which is absent in the Pr-Ni system is observed. The compounds with this type of

Table 1
Distribution of the compounds in the rare-earth–Ni–In systems on their structure types

No.	Compounds	R at. %	Structure type	Pearson code	La	Ce	Pr	Nd	Sm	Eu	Gd	Tb	Dy	Ho	Er	Tm	Yb	Lu	Y
1	RNi ₄ In ₂	8.3	YNi ₄ In ₂	tP24	+	+	+	+	+	+	+	+	+	+	+	-	-	-	+
2	RNi ₃ In ₆	10.0	LaNi ₃ In ₆	oP20	+	+	+	+	-	+	-	-	-	-	-	-	-	-	-
3	R ₂ Ni _{16.0} In _{1.0}	10.5	Th ₂ Ni ₁₇	hP38	-	-	+	-	-	-	-	-	-	-	-	-	-	-	-
4	RNi ₅ In	14.3	CeNi ₅ Sn	hP28	+	+	+	+	+	+	-	-	-	-	-	-	-	-	-
5	RNi ₄ In	16.7	MgCu ₄ Sn	cF24	-	+	+	+	+	-	+	+	+	+	+	+	+	+	+
6	RNi ₃ In ₂	16.7	HoNi _{2.6} Ga _{2.4}	hP18	+	-	+	-	-	-	-	-	-	-	-	-	-	-	-
7	RNiIn ₄	16.7	YNiAl ₄	oC24	+	+	+	+	-	+	-	-	-	-	-	-	-	+	-
8	R ₄ Ni ₇ In ₈	21.1	Ce ₄ Ni ₇ In ₈	oC76	+	+	+	+	+	-	-	-	-	-	-	-	-	-	-
9	R ₅ Ni ₆ In ₁₁	22.7	Pr ₅ Ni ₆ In ₁₁	oC44	+	+	+	+	-	-	-	-	-	-	-	-	-	-	-
10	RNi ₂ In	25.0	PrCo ₂ Ga	oP8	+	-	+	+	-	-	-	-	-	-	-	-	-	-	-
11	RNiIn ₂	25.0	MgCuAl ₂	oC16	-	-	-	-	-	+	+	+	+	-	-	-	-	-	+
12	R ₁₀ Ni ₉ In ₂₀	25.6	Ho ₁₀ Ni ₉ In ₂₀	tP78	-	-	-	-	-	-	-	-	-	+	+	+	-	+	-
13	RNiIn	33.3	ZrNiAl	hP9	+	+	+	+	⊕	-	⊕	⊕	⊕	⊕	⊕	⊕	-	⊕	⊕
14	R(Ni ₂ In) ₂	33.3	AlB ₂	hP3	⊕	⊕	⊕	⊕	⊕	+	-	-	-	-	-	-	-	-	-
15	R ₂ Ni ₂ In	40.0	Mn ₂ AlB ₂	oC10	-	-	-	-	+	-	+	+	+	+	+	+	-	+	+
16	R ₂ Ni ₂ In	40.0	Mo ₂ FeB ₂	tP10	+	+	+	+	-	-	-	-	-	-	-	-	-	-	-
17	R ₂ Ni _{2-x} In (x = 0.22)	42.0	Mo ₂ FeB ₂	tP10	-	-	-	-	+	-	+	+	+	+	+	+	-	+	+
18	R ₅ Ni ₂ In ₄	45.5	Lu ₅ Ni ₂ In ₄	oP22	-	-	-	-	-	-	-	-	-	+	+	+	-	+	-
19	R ₁₂ Ni ₆ In	63.2	Sm ₁₂ Ni ₆ In	cI38	+	-	+	+	+	-	+	-	-	-	-	-	-	-	+

+, the compound exists; ⊕, the compound has region of homogeneity; -, the compound has not been found.

structure exist in the binary R–Ni systems (R = Nd ÷ Lu, Y). The R–Ni–In systems are characterized by a lower number of compounds compared to the R–Ni–Ga systems [24] in which, due to the smaller difference between the atom sizes of Ni and Ga, the solid solutions on the base of the binary compounds are formed and many ternary compounds have a homogeneity range along the constant content of rare-earth metal. The formation of the solid solutions on the base of binary compounds and homogeneity ranges for the ternary compounds are not characteristic of the R–Ni–In systems. The compounds with the AlB₂ type structure (extension 5 at.%) and ZrNiAl [17], which are on the 33.3 at.% R section, are the exception.

It is necessary to indicate that the AlB₂-type compounds only exist with the light rare-earth metals (La, Ce, Pr, Nd, Sm, Eu) and that the compounds of these rare-earths with the ZrNiAl type structure have a constant composition (compound EuNiIn has still not been found). If a compound with the AlB₂ type structure is not formed, then a compound with a ZrNiAl type structure (R = Y, Gd, Tb, Dy, Ho, Er, Tm, Lu) has a significant homogeneity range from RNiIn composition in the direction of the increase of the In content up to composition RNi_{1-x}In_{1+x}, where x has an average value of 0.4. Samarium in this case has an intermediate position; both its compounds have homogeneity ranges. Within the homogeneity range the substitution of Ni by In is always accompanied by an increase in the volume of the cell. This observation is

consistent with the size of the Ni atom ($r_{\text{In}} > r_{\text{Ni}}$), however, both lattice parameters do not increase in all cases.

The investigated ternary compounds crystallize in 18 structure types, among which seven have new structure types. The MgCu₄Sn, YNi₄In₂, ZrNiAl and Mo₂FeB₂ types have the complete series of the isostructural compounds. But the compounds of samarium and R of the yttrium subgroup, which crystallize in the Mo₂FeB₂ type, have the small defect of Ni and the R₂Ni_{2-x}In composition ($x \sim 0.22$). The LaNi₃In₆, CeNi₅Sn, YNiAl₄, Ce₄Ni₇In₈, Pr₅Ni₆In₁₁, AlB₂ and Sm₁₂Ni₆In structure types are characteristic of compounds with R from the cerium subgroup, and Ho₁₀Ni₉In₂₀, Mn₂AlB₂ and Lu₅Ni₂In₄ structure types are characteristic of compounds with R from the yttrium subgroup. Most compounds of the R–Ni–In systems are related to the binary compounds. They can be superstructures to them, contain their fragments or be the members of the homological series which are based on more simple types (Table 2).

The structure types in which the compounds of the R–Ni–In systems crystallize (except the types Th₂Ni₁₇, Ho₉Ni₉In₂₀ and Sm₁₂Ni₆In with large unit cells) can be divided into three groups. The first one contains the compounds with the large Ni content (YNi₄In₂, CeNi₅Sn and MgCu₄Sn structure types). These compounds have four layers altering in the shortest direction which is equal to ~ 0.5 nm. Cubic structure MgCu₄Sn when presented in hexagonal aspect, in

Table 2
Relations between the structures in the rare-earth-Ni-In systems

I. Superstructure	Structure
YNi ₆ In ₂	→ Ce(Ni _{0.45} Mn _{0.55}) ₁₁
MgCu ₄ Sn	→ AuBe ₅ → MgCu ₂
MgCuAl ₂	→ PuBr ₃
ZrNiAl	→ Fe ₂ P
Mo ₂ FeB ₂	→ U ₃ Si ₂
II. Structure	Fragments
YNi ₆ In ₂	= CeMg ₂ Si ₂ + Zr ₄ Al ₃
LaNi ₃ In ₆	= MgCuAl ₂ + 'Ni ₂ In ₄ '
CeNi ₅ Sn	= CaCu ₅ + 'CeNi ₂ In' + Ni ₃ In
Ce ₄ Ni ₇ In ₈	= CeMg ₂ Si ₂ + AuCu ₃ + CsCl + HoNi _{2.6} Ga _{2.4}
Pr ₅ Ni ₆ In ₁₁	= CeMg ₂ Si ₂ + AuCu ₃ + CsCl + CaCu ₅
PrCo ₂ Ga	= CsCl + CaCu ₅
Mo ₂ FeB ₂	= CsCl + AlB ₂
Mn ₂ AlB ₂	= CsCl + AlB ₂
Lu ₅ Ni ₂ In ₄	= CsCl + AlB ₂

case of CeNi₄In has $a \approx 0.5$ nm, $c \approx 1.22$ nm. The second group (LaNi₃In₆, Ce₄Ni₇In₈, Pr₅Ni₆In₁₁, YNiAl₄ and MgCuAl₂ structure types) contains the compounds with a bigger In content; they have two layers in the shortest direction equal to ~ 0.45 nm. It is possible to include the compounds with the PrCo₂Ga type structure into this group, which has a lower In content, but has two layers with the shortest lattice parameter of ~ 0.45 nm. The compounds with the average R content (ZrNiAl, AlB₂, Mo₂FeB₂, Mn₂AlB₂ and Lu₅Ni₂In₄ structure types), which are similar to those of the second group have two layers and form the third group. But the shortest period of these compounds is less than one (~ 0.4 nm) in spite of a larger R content.

The compounds of the first group are characteristic of high values of coordination number (CN) of all atoms, which slowly decrease in the direction of the second and third group. If coordination polyhedra of the smallest atoms (Ni) for a compound of the first group are icosahedra (or their defect derivatives) then for the compounds of the second and the third group they are trigonal prisms with three or four additional atoms. The CN of the In atoms changes in the same way and for the compounds of the second group coordination polyhedra are only deformed cubo-octahedra (CN = 12).

It was underlined that at the transition from the second to third group of the compounds in spite of increasing the rare-earth content, which has a bigger atom size than In or Ni, the decreasing of the shortest period observed; the RNiAl (ZrNiAl structure type) [24] compounds isostructural with the respective indium compounds having smaller volume of the unit cell were characterized by a bigger value of the short-

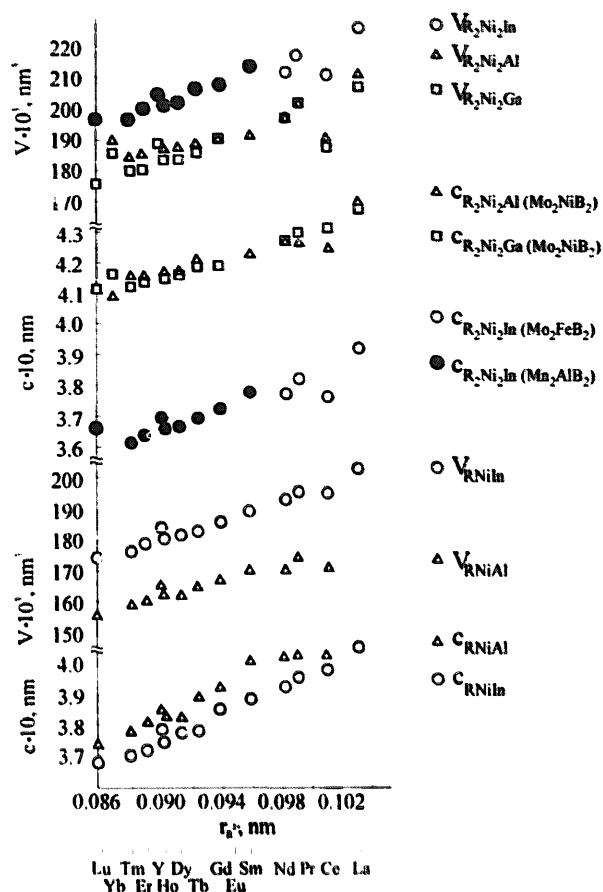


Fig. 1. Change of the volume and the shortest c period for some indides, gallides and aluminides depending on size of R^{3+} ions.

est period. Analogously, the R_2Ni_2Al and R_2Ni_2Ga compounds (Mo_2NiB_2 structure type) [24] have also bigger values of the shortest lattice parameter than those relative to the R_2Ni_2In compounds (Mo_2FeB_2 and Mn_2AlB_2 structure type). In spite of the fact that the last compounds are not isostructural in our opinion, such a comparison is correct because in all cases the unit cell contains 10 atoms ($4R + 4Ni + 2X$) (Fig. 1). Analogous disparity of the shortest lattice parameter is characteristic of $RCuIn$ and $RCuAl$ with the structure type ZrNiAl. For the compounds rich in X component (for example YNiAl₄) for all known compounds of indium, all the lattice parameters are bigger than those of the relevant Al or Ga compounds [24].

Indicated disparity can be explained by the strong polarization of the In atoms; spheroids having a value of the small semiaxis less than radius Al or Ga atom lie on the plane perpendicular to the shortest period and as a result the value of this period for indides is smaller than for that in the aluminides or gallides. The analogous polarization of In atoms is obviously characteristic of the compound with the AlB₂ and Lu₅Ni₂In₄-types. From this it is possible to explain

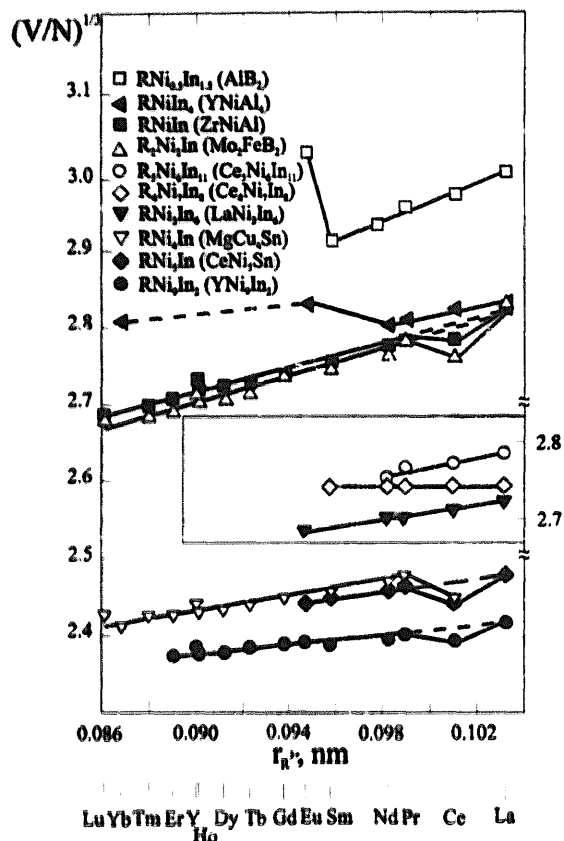


Fig. 2. Dependence of the linear parameter $(V/N)^{1/3}$ (V is a volume of the unit cell, N is a number of atoms per unit cell) on size of R^{3+} ion.

the existence of antiferromagnetic, in some cases, change of periods within the homogeneity range of the compounds with the $ZrNiAl$ or AIB_2 type structure.

Change of the linear parameter $(V/N)^{1/3}$ (where V is a volume of the unit cell, N is a number of atoms per unit cell) depending on the size of the R^{3+} ion, according to Shannon [25] for the series of the isostructural compounds are shown in Fig. 2. This change confirms with the effect of the lanthanide contraction. It is seen that for the Ni-rich compounds of cerium, a negative deviation from the linearity was observed. This shows the intermediate valence state, or valence equal to four for $CeNi_3In$, $CeNi_2In$, $CeNiIn$ and Ce_2Ni_2In . It was confirmed by the experimental investigation that in $CeNi_3In$ there is Ce^{+4} [26], in Ce_2Ni_2In , according to Gordon et al. [32], Ce is in valence state +4, according to Kaczorowski et al. [33] it is in intermediate valence state as well as in $CeNiIn$ [29–31]. According to Pöttgen [27], in $CeNiIn_4$ there is Ce^{+3} ; the same was reported for $Ce_3Ni_6In_{11}$ [28]. The Ni-rich compounds of Eu and Yb contain these elements in the valence state of +3, and In-rich compounds contain Eu and Yb in the valence state of less than +3 ($EuNiIn_4$, $YbNiIn_4$, $Eu(Ni,In)_2$, $EuNiIn_2$). The investigations of the

$EuNiIn_4$ compound show that in this compound Eu is in a valence state of +2 [34].

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